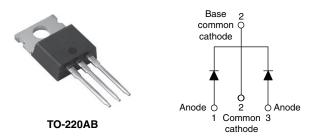


Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY				
Package	TO-220AB			
I _{F(AV)}	2 x 20 A			
V _R	45 V			
V _F at I _F	0.58 V			
I _{RM} max.	95 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Common cathode			
E _{AS}	20 mJ			

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN
- Guard ring for enhanced ruggedness and long
 term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform (per device)	40	A		
V _{RRM}		45	V		
I _{FRM}	$T_C = 118 \ ^{\circ}C \ (per \ leg)$	40	А		
I _{FSM}	t _p = 5 μs sine	900	A		
V _F	20 A _{pk} , T _J = 125 °C	0.58	V		
TJ	Range	- 65 to 150	°C		

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBR4045CTPbF	VS-MBR4045CT-N3	UNITS		
Maximum DC reverse voltage	V _R	45	45	V		
Maximum working peak reverse voltage	V _{RWM}	45	45	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS		VALUES	UNITS				
Maximum average	per leg		$I_{F(AV)}$ T _C = 118 °C, rated V _R				20	
forward current	per device	'F(AV)			40			
Peak repetitive forward current p	ber leg	I _{FRM}	RM Rated V_R , square wave, 20 kHz, $T_C = 118 \text{ °C}$		40	А		
Maximum peak one cycle non-repetitive surge current per leg		Isou	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	900			
		IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	210			
Non-repetitive avalanche energy	v per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3 \text{ A}, L = 4.40 \text{ mH}$		20	mJ		
Repetitive avalanche current per	r leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А		

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T 05.00	0.60	V
Movimum forward valtage drep	V (1)	40 A	T _J = 25 °C	0.78	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T 405 00	0.58	
		40 A	T _J = 125 °C	0.75	
	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	1	mA
Maximum instantaneus reverse current		T _J = 100 °C		50	
		T _J = 125 °C		95	
Maximum junction capacitance	CT	V_R = 5 V_{DC} , (test signal range 100 kHz to 1 MHz) 25 °C		900	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		- 65 to 150	о°С		
Maximum storage temperature range	T _{Stg}		- 65 to 175	U		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5			
Typical thermal resistance, case to heatsink		Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (For D ² PAK and TO-262)	50			
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torque		Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maximum		Non-Iublicated threads	12 (10)	(lbf ⋅ in)		
Marking device		Case style TO-220AB	MBR4	045CT		

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VS-MBR4045CTPbF, VS-MBR4045CT-N3

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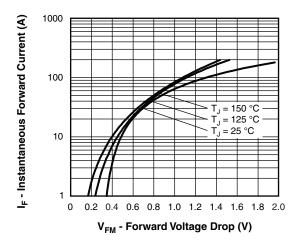


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

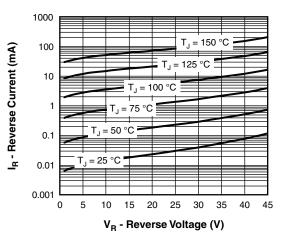


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

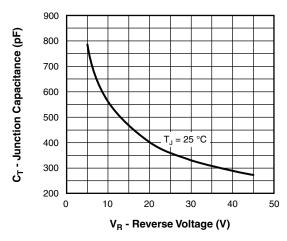
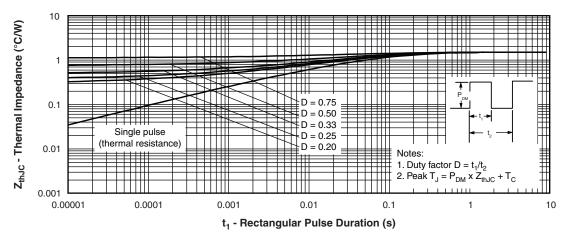


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



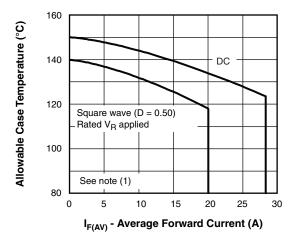


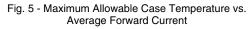
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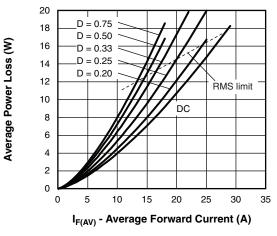


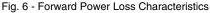
VS-MBR4045CTPbF, VS-MBR4045CT-N3

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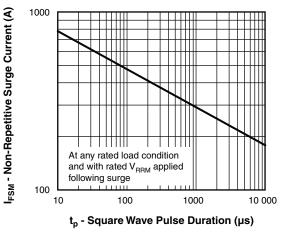


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

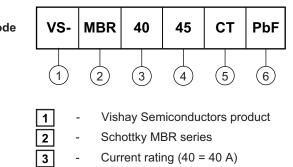


VS-MBR4045CTPbF, VS-MBR4045CT-N3

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ORDERING INFORMATION TABLE

Device code



Current rating (40 = 40 A)

- Voltage rating (45 = 45 V)
- CT = Essential part number
- Environmental digit _

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5 6

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-MBR4045CTPbF	50	1000	Antistatic plastic tube		
VS-MBR4045CT-N3	50	1000	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95296			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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